

Absolute maximum ratings

($T_a=25^\circ\text{C}$)

Symbol	Specification	Unit
V_{CBO}	120	V
V_{CEO}	120	V
V_{EBO}	6	V
I_c	5	A
I_{CP}	8 ($PW \leq 1\text{ms}$, $D_u \leq 50\%$)	A
I_B	0.5	A
I_F	5 ($PW \leq 0.5\text{ms}$, $D_u \leq 25\%$)	A
I_{FSM}	8 ($PW \leq 10\text{ms}$, single)	A
V_R	120	V
P_T	5 ($T_a=25^\circ\text{C}$)	W
	25 ($T_c=25^\circ\text{C}$)	
V_{ISO}	1000 (Between fin and lead pin, AC)	V_{rms}
T_j	150	$^\circ\text{C}$
T_{stg}	-40 to +150	$^\circ\text{C}$
θ_{j-c}	5	$^\circ\text{C/W}$

Electrical characteristics

($T_a=25^\circ\text{C}$)

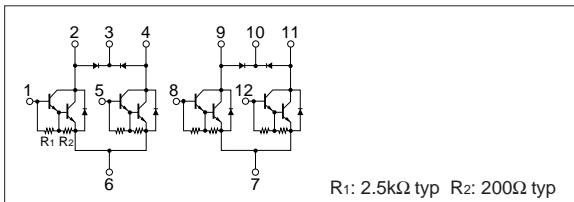
Symbol	Specification			Unit	Conditions
	min	typ	max		
I_{CBO}			10	μA	$V_{CB}=120\text{V}$
I_{EBO}			10	mA	$V_{EB}=6\text{V}$
V_{CEO}	120			V	$I_c=25\text{mA}$
h_{FE}	2000	5000	15000		$V_{CE}=2\text{V}$, $I_c=3\text{A}$
$V_{CE(sat)}$		1.0	1.5	V	$I_c=3\text{A}$, $I_B=3\text{mA}$
$V_{BE(sat)}$		1.6	2.0	V	
t_{on}		0.5		μs	$V_{CC} \approx 30\text{V}$, $I_c=3\text{A}$, $I_{B1}=-I_{B2}=3\text{mA}$
t_{stg}		5.5		μs	
t_f		1.5		μs	

Diode for flyback voltage absorption

($T_a=25^\circ\text{C}$)

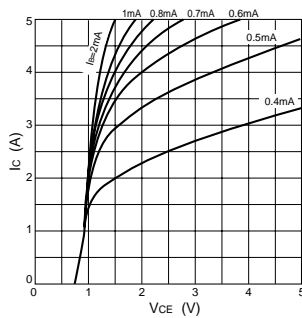
Symbol	Specification			Unit	Conditions
	min	typ	max		
V_R	120			V	$I_R=10\mu\text{A}$
V_F			1.2	V	$I_F=1\text{A}$
I_R			10	μA	$V_R=120\text{V}$
t_{rr}		100		ns	$I_F=\pm 100\text{mA}$

Equivalent circuit diagram

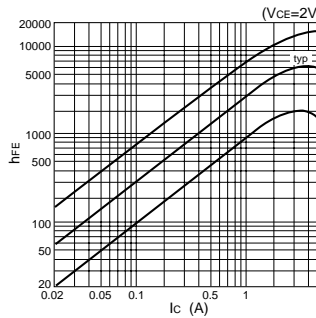


Characteristic curves

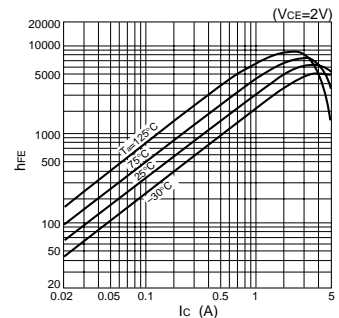
I_c - V_{CE} Characteristics (Typical)



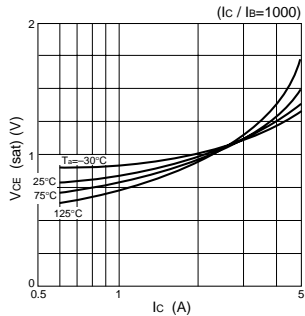
h_{FE} - I_c Characteristics (Typical)



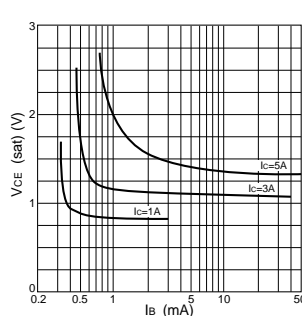
h_{FE} - I_c Temperature Characteristics (Typical)



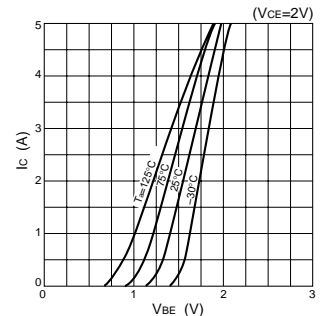
$V_{CE(sat)}$ - I_c Temperature Characteristics (Typical)



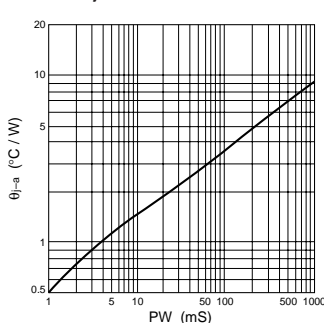
$V_{CE(sat)}$ - I_B Characteristics (Typical)



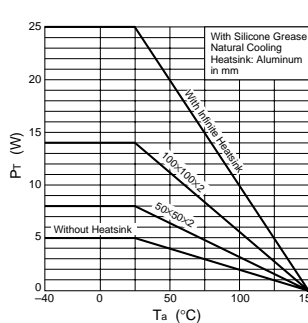
I_c - V_{BE} Temperature Characteristics (Typical)



θ_{j-a} - PW Characteristics



P_r - T_a Characteristics



Safe Operating Area (SOA)

